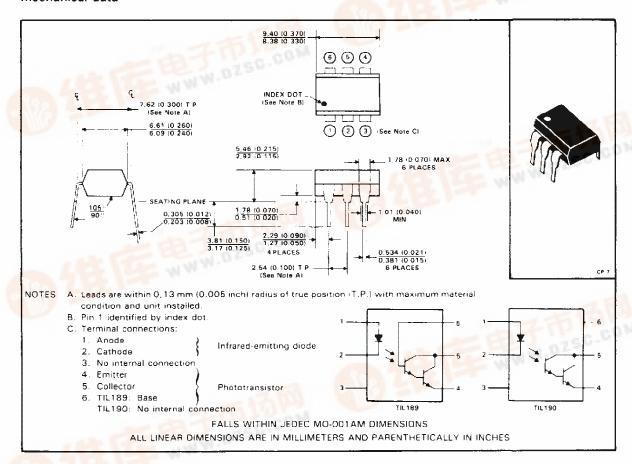
TIL189-1 THRU TIL189-4 TIL190-1 THRU TIL190-4 OPTOCOUPLERS/OPTOISOLATORS SOOS038A D2987, JANUARY 1987 – REVISED JULY 1989

- High Direct-Current Transfer Ratios, 500%
 Minimum at IF = 10 mA and Up to 1500%
 at IF = 2 mA with Choice of Four Categories
- Plastic Dual-In-Line Package
- High-Voltage Electrical Isolation, 3.535 kV Peak (2.5 kV rms)
- Gallium Arsenide Diode Infrared Source
 Optically Coupled to a Silicon N-P-N Darlington
 Phototransistor
- No Base Lead Connection on TIL190 for High-EMI Environment
- UL Recognized File #E65085

description

The TIL189 and TIL190 Optocouplers are designed for use in applications that require high current transfer ratio and high voltage isolation between the input and output. The TIL189 has the base connected for applications where a base signal or resistor is required. The TIL190 is designed with no internal base connection for applications where high base-noise immunity is desired. Users can select from four different current gains (TIL189-1 through TIL189-4 and TIL190-1 through TIL190-4).

mechanical data





TIL189-1 THRU TIL189-4 TIL190-1 THRU TIL190-4 OPTOCOUPLERS/OPTOISOLATORS

absolute maximum ratings at 25 °C free-air temperature (unless otherwise noted)

Input-to-output voltage
Collector-emitter voltage (see Note 1)
Emitter-collector voltage
Emitter-base voltage (TIL189)
Input diode reverse voltage
Input diode continuous forward current at (or below)
25 °C free-air temperature (see Note 2)
Continuous power dissipation at (or below) 25°C free-air temperature:
Infrared-emitting diode (see Note 3)
Phototransistor (see Note 3)
Total, infrared-emitting diode plus phototransistor (see Note 4)
Storage temperature range
Lead temperature 1,6 mm (1/16-inch) from case for 10 seconds

- NOTES: 1. This value applies when the base-emitter diode is open circuited.
 - 2. Derate linearly to 100°C free-air temperature at the rate of 1.33 mA/°C
 - 3. Derate linearly to 100°C free-air temperature at the rate of 2 mW/°C.
 - 4. Derate linearly to 100 °C free-air temperature at the rate of 3.33 mW/ °C.

TIL189-1 THRU TIL189-4 TIL190-1 THRU TIL190-4 OPTOCOUPLERS/OPTOISOLATORS

electrical characteristics at 25 °C free-air temperature (unless otherwise noted)

PARAMETER			TC0	7707 001151710110		TIL189		TIL190			
			IEK	TEST CONDITIONS	MIN TYP		MAX	MIN	TYP	MAX	UNIT
V(BR)CBO	Collector-base BR)CBO breakdown voltage			IC = 10 µA, IE = 0, IE = 0	100				-		٧
V(BR)CEO	Collector-e breakdowi			$I_C = 1 \text{ mA}, I_B = 0,$ $I_F = 0$	55			55			V
V _{(BR)EBO}	Emitter-ba	-	oltage	$I_{E} = 10 \mu\text{A}, I_{C} = 0,$ $I_{F} = 0$	14						٧
V(BR)ECO Emitter-collector breakdown voltage				IE = 100 μA, IF = 0				7			>
Input diode static		V _A = 3 V			10			10	μΔ		
	ļ		TIL189-1, TIL190-1		5			5			
	Photo	TIL 189-3, TIL 190-3 transistor TII 189-4, TII 190-4		V _{CE} = 1 V, I _F = 2 mA,	10 20			10		_	
On-sta I _{Clon)} collect curren	state transi:		TII 189-4 TII 190-4	4	30			30			mΑ
	1		V _{CE} = 1 V, I _F = 10 mA, I _B = 0	50	-		50				
	Photo	dioc	fe operation	V _{CB} = 1 V, I _F = 10 mA, I _E = 0	5	15					μА
Off-state collector current		$V_{CE} = 10 \text{ V, Ip} = 0,$ $I_{B} = 0$		1	100		1	100	nA		
Transistor static hFE forward current transfer ratio		V _{CE} = 1 V, I _C = 10 mA, I _F = 0		25000							
Input diode static V _F forward voltage		IF = 10 mA		1.2	1.5		1.2	1.5	V		
Collector-emitter VCE(sat) saturation voltage		$I_C = 50 \text{ mA}, I_F = 10 \text{ mA},$ $I_B = 0$		0.87	1		0.87	1	٧		
Input-to-output FID internal resistance		Vin-out = ±500 V. See Note 5	1011			1011			Ω		
Input-to-output Cio capacitance			ıt	Vin-out = 0, f = 1 mHz, See Note 5		1	1.3		1	1.3	pF

NOTE 5: These parameters are measured batween both input-diode leads shorted together and all the phototransistor leads shorted together.

switching characteristics at 25 °C free-air temperature

PARAMETER	TEST C	Į.	TIL189			TIL190			
, Anameren	1631 6	MIN	TYP	MAX	MIN	TYP	MAX	UNIT	
t, Rise time	V _{CC} = 10 V.	I _{C(on)} = 10 mA.		100			100		μs
tf Fall time	R _L = 100 Ω,	see Figure 1		100			100		μS

PARAMETER MEASUREMENT INFORMATION

Adjust amplitude of input pulse for I_{C(on)} = 10 mA 47 🛭 INPUT OUTPUT 90% VCC **- 100** Ω TEST CIRCUIT **VOLTAGE WAVEFORMS**

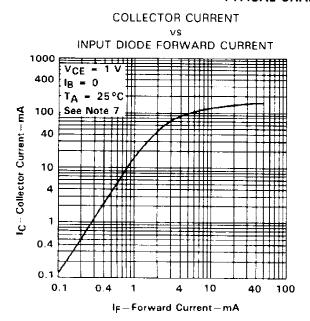
NOTES: A. The input waveform is supplied by a generator with the following characteristics: $Z_0 = 50 \Omega$, $t_r = \pm 15$ ns, duty cycle $\approx 1\%$ B. The output waveform is monitored on an oscilloscope with the following characteristics: $t_{\rm f} \leq 12$ ns, $R_{\rm 1} \geq 1$ M Ω , $C_{\rm 1D} \leq 20$ pF.

FIGURE 1. SWITCHING TIMES

TYPICAL CHARACTERISTICS FORWARD CURRENT COLLECTOR CURRENT V5 ٧s FORWARD VOLTAGE COLLECTOR-EMITTER VOLTAGE 160 200 180 140 ic = 9 mA 160 IC - Collector Current - mA ₹ 120 140 Forward Current 100 120 TA = 25°C See Note 6 80 100 80 60 - 70°C 60 IF = 2 mA 40 ۳ 40 TA = -55°C 20 20 0 0 0 0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6 1.8 2.0 0 0.5 1.0 1.5 2.0 2.5 VF-Forward Voltage-V VCE - Collector-Emitter Voltage - V FIGURE 2 FIGURE 3

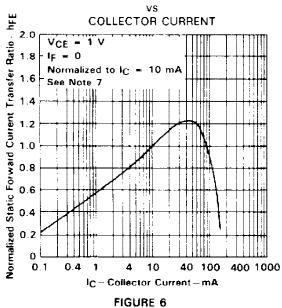
NOTE 6. Pulse operation is required for operation beyond limits shown by the dashed line.

TYPICAL CHARACTERISTICS

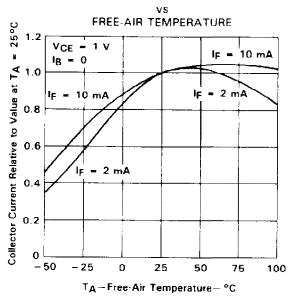


TIL189
NORMALIZED TRANSISTOR STATIC
FORWARD CURRENT TRANSFER RATIO

FIGURE 4



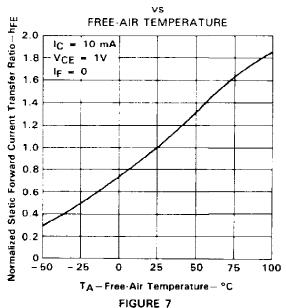
RELATIVE ON-STATE COLLECTOR CURRENT



TIL189

NORMALIZED TRANSISTOR STATIC
FORWARD CURRENT TRANSFER RATIO

FIGURE 5

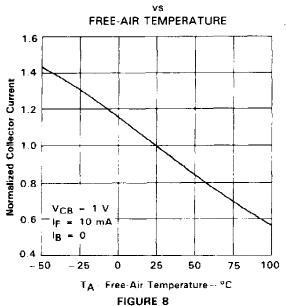


NOTE 7: These parameters were measured using pulse techniques $t_{\text{W}} = 1$ ms, duty cycle $\leq 2\%$.

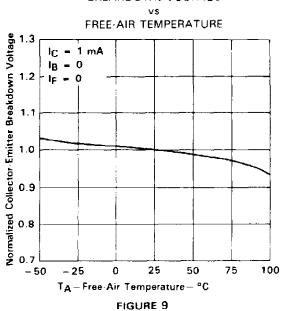


TYPICAL CHARACTERISTICS

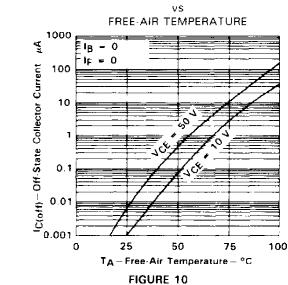
TIL189 RELATIVE ON-STATE COLLECTOR CURRENT (PHOTODIODE OPERATION)



RELATIVE COLLECTOR-EMITTER BREAKDOWN VOLTAGE



OFF STATE COLLECTOR CURRENT



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PACKAGE OPTION ADDENDUM

8-Apr-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TIL189-1	OBSOLETE	PDIP	N	6	TBD	Call TI	Call TI
TIL189-3	OBSOLETE	PDIP	N	6	TBD	Call TI	Call TI
TIL189-4	OBSOLETE	PDIP	N	6	TBD	Call TI	Call TI
TIL190-1	OBSOLETE	PDIP	N	6	TBD	Call TI	Call TI
TIL190-2	OBSOLETE	PDIP	N	6	TBD	Call TI	Call TI
TIL190-3	OBSOLETE	PDIP	N	6	TBD	Call TI	Call TI
TIL190-4	OBSOLETE	PDIP	N	6	TBD	Call TI	Call TI

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

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TBD: The Pb-Free/Green conversion plan has not been defined.

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Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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